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IN THE SPECIFICATION:

Page 13, line 22 to Page 14, line 16, please amend as follows:

(Thirty-ninth embodiment)

There is provided a method of fabricating a liquid crystal display device comprising: fabricating a first bottom-gate TFT array substrate including forming at least a gate wiring line metal film, a gate insulating film, and a semiconductor film on a surface of an insulating substrate; by photolithography, sequentially etching the semiconductor film, the gate insulating film, and the gate wiring line metal film, using a first pattern; oxidizing side surfaces of portions of a gate wiring line metal film pattern to be formed into gate wiring lines and gate electrodes; forming a contact metal film and a metal electrode film; and by photolithography, etching part of the metal electrode film, the contact metal film, and the semiconductor film, using a second pattern; forming an alignment film on the first substrate; forming an alignment film on a surface of a counter electrode side of a second color filter substrate having a counter transparent electrode formed thereon; adhering and fixing the first and second substrates ~~and the color filter substrate~~ at the periphery thereof such that the substrates are

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arranged with the two alignment films facing inside and with a predetermined gap maintained between the substrates; and injecting a specified liquid crystal between the first and second substrates.

Page 24, line 8 to page 25, line 1, please amend as follows:

(Seventy-fifth embodiment)

There is provided a method of fabricating a liquid crystal display device comprising: fabricating a first bottom-gate TFT array substrate including forming at least a gate wiring line metal film, a gate insulating film, and a semiconductor film on a surface of an insulating substrate; by photolithography, sequentially etching the semiconductor film, the gate insulating film, and the gate wiring line metal film, using a first pattern; oxidizing side surfaces of portions of a gate wiring line metal film pattern to be formed into gate wiring lines, gate electrodes, and first comb-shaped electrodes; forming a contact metal film layer and a metal electrode film; by photolithography, etching part of the metal electrode film, the contact metal film layer, and the semiconductor film, using a second pattern;

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forming an alignment film on the first substrate; forming an alignment film on a surface of a counter electrode side of a second color filter substrate; adhering and fixing the first and second substrates ~~and the color filter substrate~~ at the periphery thereof such that the substrates are arranged with the two alignment films facing inside and with a predetermined gap maintained between the substrates; and injecting a specified liquid crystal between the first and second substrates.

Page 54, lines 4-15, please amend as follows:

First, there were provided a TFT array substrate for the IPS mode device, similar to that of Example 2-5, fabricated using two masks, more specifically, a first TFT array substrate including a first comb-shaped electrode group and a second comb-shaped electrode group arranged in a matrix and a transistor group that drives the first comb-shaped electrode group; and a ~~second comb-shaped electrode group; and a color filter substrate including a~~ second color filter substrate including a color filter group placed opposite to the first and second electrode groups. Over each of the substrates, by a conventional method, a polyimide resin was applied and cured, and the resulting films were

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subjected to rubbing, thus producing liquid crystal alignment films.

Page 58, line 15 to Page 59, line 1, please amend as follows:

Example 2-8

The actual fabrication process of a liquid crystal display device using the above-described TFT array substrate is described.

First, there were provided a TFT array substrate for the IPS mode device, similar to that of Example 2-7, fabricated using two masks, more specifically, a first TFT array substrate including a first comb-shaped electrode group and a second comb-shaped electrode group arranged in a matrix and a transistor group that drives the ~~second~~first comb-shaped electrode group; and a second color filter substrate including a color filter group placed opposite to the first and second electrode groups. Over each of the substrates, by a conventional method, a polyimide resin was applied and cured, and the resulting films were subjected to rubbing, thus producing liquid crystal alignment films.